

Low Cost, High Voltage Operational Amplifiers

Features

- Wide Supply Range of 3V ~ 30V
- Large DC Voltage Gain: 100dB
- Quiescent Current per Amplifier: 250µA
- Gain Bandwidth Product: 1.0 MHz
- Slew Rate: 0.35V/µs
- Unity Gain Stable
- Input Common-mode Voltage Range Includes negative Rails
- Differential Input Voltage Range Equal to the Power Supply Voltage
- Packaging Available
 LM321 available in SOT23-5/SOP8
 LM358 available in SOP8/MSOP8
 LM324 available in SOP14/TSSOP14

Applications

- Power Supplies and Mobile Chargers
- Motor Control
- AC Inverters
- White Goods
- Battery or Solar Powered Systems

General Description

The LM321 (single), LM358 (dual) and LM324 (quad) are low-power, low cost operational amplifiers (op amps) operated on 3V to 30V supplies. Despite their wide supply range, the LM358 family provides excellent overall performance and versatility. They have high differential input voltage capability. The common-mode input voltage range includes ground, enabling direct sensing near ground.

The LM358 family is unity gain stable and has a gain bandwidth product of 1.1MHz (typical). They provide high CMRR and PRSS performance and can operate from a single supply voltage as well as dual supply voltages. The LM358 family can be designed into a wide range of applications at an economical price without sacrificing basic performance.

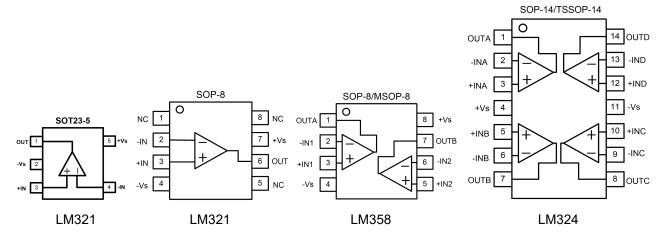
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Rev1.1



1. Pin Configuration and Functions



Pin Functions

Name	Description	Note
+Vs	Positive power supply	A bypass capacitor of 0.1µF as close to the part as possible should be placed between power supply pins or between supply pins and ground.
-Vs	Negative power supply or ground	If it is not connected to ground, bypass it with a capacitor of $0.1\mu F$ as close to the part as possible.
-IN	Negative input	Inverting input of the amplifier. Voltage range of this pin can go from -Vs -0.3V to +Vs - 1V.
+IN	Positive input	Non-inverting input of the amplifier. This pin has the same voltage range as –IN.
OUT	Output	The output voltage range extends to within millivolts of each supply rail.
NC	No connection	

2. Package and Ordering Information

Model	Channel	Order Number	Package	Package Option	Marking Information
LM321	1	LM321TR	SOT23-5	Tape and Reel, 3000	C321HV
		LM321SR	SOP-8	Tape and Reel, 3000	COS321HV
1 M250	2	LM358SR	SOP-8	Tape and Reel, 3000	COS358HV
LM358	2	LM358MR	MSOP-8	Tape and Reel, 3000	COS358HV
1 M204	4	LM324SR	SOP-14	Tape and Reel, 3000	COS324HV
LM324		LM324TR	TSSOP-14	Tape and Reel, 3000	COS324HV



3. Product Specification

3.1 Absolute Maximum Ratings⁽¹⁾

Parameter	Rating	Units
Power Supply: +Vs to -Vs	32 or ±16	V
Input Voltage	-0.3 to 32	V
Differential Input Voltage	±16	V
Input Current (DC)	5	mA
Storage Temperature Range	-65 to 150	°C
Junction Temperature	150	°C
Operating Temperature Range	-40 to 125	°C
ESD Susceptibility, HBM	2000	V

(1) Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

3.2 Thermal Data

Parameter	Rating	Unit
Package Thermal Resistance, R _{eJA} (Juntion-to-ambient)	190 (SOT23-5) 206 (MSOP8) 155 (SOP8) 105 (TSSOP14) 82 (SOP14)	°C/W

3.3 Recommended Operating Conditions

Parameter	Rating	Unit
DC Supply Voltage	3 ~ 30	V
Input common-mode voltage range	-Vs ~ +Vs -1.5	V
Operating ambient temperature	-40 to +85	°C



3.4 Electrical Characteristics

(+Vs=+5V, -Vs=0, V_{CM}=Vs/2, T_A=+25°C, R_L=10k Ω to Vs/2, unless otherwise noted)

Parameter	Symbol	Conditions	Min	Тур	Мах	Unit
Input Characteristics						
Input Offset Voltage	Vos			2.0	5.0	mV
Input Offset Voltage Drift	ΔV _{os} /ΔT	-40 to 125°C		7	15	μV/°C
Input Bias Current	IB			45	250	nA
Input Offset Current	los			3	50	nA
Common-Mode Voltage Range	V _{СМ}	+V _S = 30V	0		+Vs -1.5	V
Common-Mode Rejection Ratio	CMRR	V _{CM} =0 to (+Vs -1.5)	65	90		dB
Large Signal Voltage Gain	A _{OL}	V_0 =1 to11V, +V _S = 15V, R _L = 2 kΩ		100		V/mV
Output Characteristics	1		1	I		
		+V _S = 18V, R _L =2kΩ	16			V
Output Voltage Swing from Rail	V _{OH}	+V _S = 18V, R _L =10kΩ	16.3			V
	Vol	+V _S = 5V, R _L =10kΩ		5	20	mV
Output Source Current	I _{SR}	+V _S =15V, V _o =2V, V _{id} =1V	20	40		mA
	ISK	+V _S =15V, V _o =2V, V _{id} = -1V	10	15		mA
Output Sink Current		$+V_{S} = 15V, V_{o} = 0.2V, V_{id} = -1V$	12	50		μA
Short-Circuit Current to Ground	I _{sc}	+V _S =15V		40	60	mA
Power Supply	1		1	1		
Operating Voltage Range	Vs		3		30	V
Power Supply Rejection Ratio	PSRR	V _s = +1.8V to +5.5V	80	100		dB
		V _S = +30V		250	500	μA
Quiescent Current / Amplifier	IQ	V _S = +5V		200	400	μA
Dynamic Performance	•					
Gain Bandwidth Product	GBWP	G=+1		1.0		MHz
Slew Rate	SR	G = +1 , 2V Output Step		0.35		V/µs



4.0 Application Notes

Driving Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases, and the closed loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity gain buffer (G = +1) is the most sensitive to capacitive loads, but all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g., > 100 pF when G = +1), a small series resistor at the output (R_{ISO} in Figure 1) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. It does not, however, improve the bandwidth.

To select R_{ISO} , check the frequency response peaking (or step response overshoot) on the bench. If the response is reasonable, you do not need R_{ISO} . Otherwise, start R_{ISO} at 1 k Ω and modify its value until the response is reasonable.

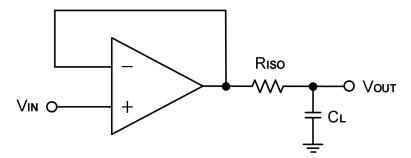


Figure 1. Indirectly Driving Heavy Capacitive Load

An improvement circuit is shown in Figure 2. It provides DC accuracy as well as AC stability. R_F provides the DC accuracy by connecting the inverting signal with the output, C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.

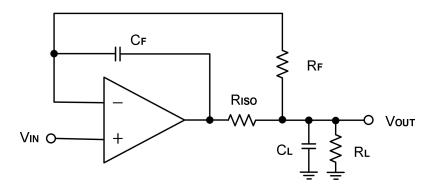


Figure 2. Indirectly Driving Heavy Capacitive Load with DC Accuracy



For noninverting configuration, there are two others ways to increase the phase margin: (a) by increasing the amplifier's gain or (b) by placing a capacitor in parallel with the feedback resistor to counteract the parasitic capacitance associated with inverting node, as shown in Figure 3.

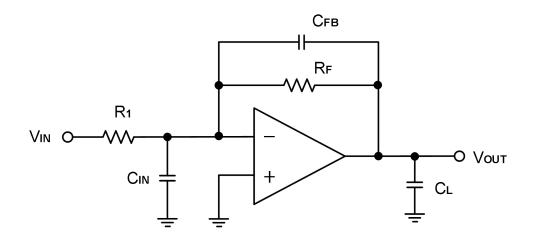


Figure 3. Adding a Feedback Capacitor in the Noninverting Configuration

Power-Supply Bypassing and Layout

The LM321/2/4 operates from a single +3V to +30V supply or dual $\pm 1.5V$ to $\pm 15V$ supplies. For single-supply operation, bypass the power supply +Vs with a 0.1µF ceramic capacitor which should be placed close to the +Vs pin. For dual-supply operation, both the +Vs and the -Vs supplies should be bypassed to ground with separate 0.1µF ceramic capacitors. 2.2µF tantalum capacitor can be added for better performance.

The length of the current path is directly proportional to the magnitude of parasitic inductances and thus the high frequency impedance of the path. High speed currents in an inductive ground return create an unwanted voltage noise. Broad ground plane areas will reduce the parasitic inductance. Thus a ground plane layer is important for high speed circuit design.

Typical Application Circuits

Differential Amplifier

The circuit shown in Figure 4 performs the differential function. If the resistors ratios are equal (R₄ / R₃ = R₂ / R₁), then $V_{OUT} = (V_{IP} - V_{IN}) \times R_2 / R_1 + V_{REF}$.



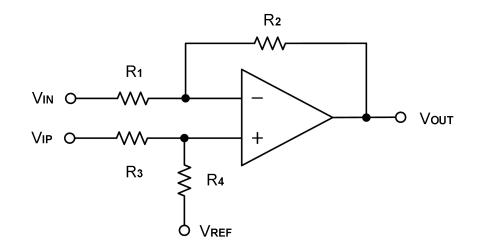


Figure 4. Differential Amplifier

Low Pass Active Filter

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting terminal of the amplifier. If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task, as Figure 5. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to follow this guideline can result in reduction of phase margin. The large values of feedback resistors can couple with parasitic capacitance and cause undesired effects such as ringing or oscillation in high-speed amplifiers. Keep resistors value as low as possible and consistent with output loading consideration.

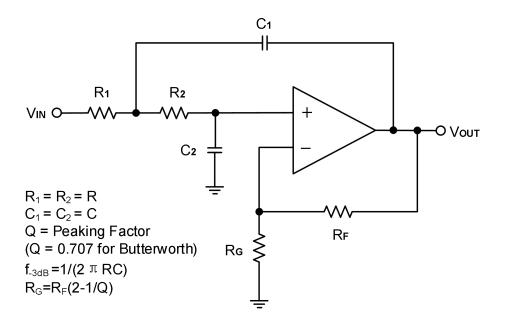


Figure 5. Two-Pole Low-Pass Sallen-Key Active Filter



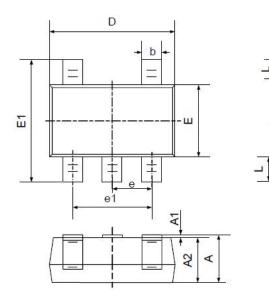
5. Package Information

5.1 SOT23-5 (Package Outline Dimensions)

θ

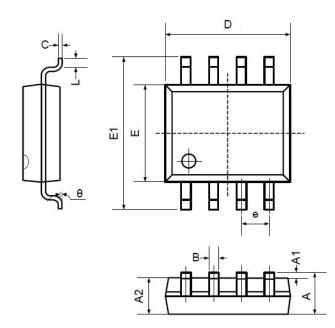
С

0.20



Symbol		nsions imeters	Dimensions In Inches	
	Min	Max	Min	Max
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.400	0.012	0.016
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
е	0.950TYP		0.03	7TYP
e1	1.800	2.000	0.071	0.079
L	0.700REF		0.028	BREF
L1	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

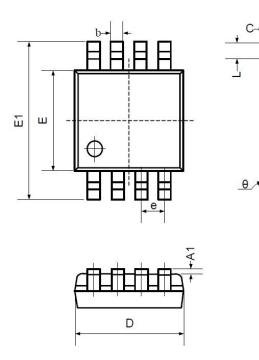
5.2 SOP8 (Package Outline Dimensions)



Symbol		nsions meters	Dimensions In Inches	
	Min	Max	Min	Max
А	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
В	0.330	0.510	0.013	0.020
С	0.190	0.250	0.007	0.010
D	4.780	5.000	0.188	0.197
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.248
е	1.27	DTYP	0.050	OTYP
L	0.400	1.270	0.016	0.050
θ	0 °	8°	0°	8°

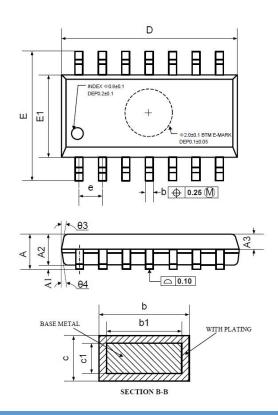


5.3 MSOP8 (Package Outline Dimensions)



Symbol		nsions meters	Dimensions In Inches		
	Min	Max	Min	Max	
A	0.800	1.200	0.031	0.047	
A1	0.000	0.200	0.000	0.008	
A2	0.760	0.970	0.030	0.038	
b	0.30	TYP	0.012 TYP		
С	0.15	TYP	0.006 TYP		
D	2.900	3.100	0.114	0.122	
e	0.65	TYP	0.026 TYP		
E	2.900	3.100	0.114	0.122	
E1	4.700	5.100	0.185	0.201	
L	0.410	0.650	0.016	0.026	
θ	0°	6°	0°	6°	

5.4 SOP14 (Package Outline Dimensions)



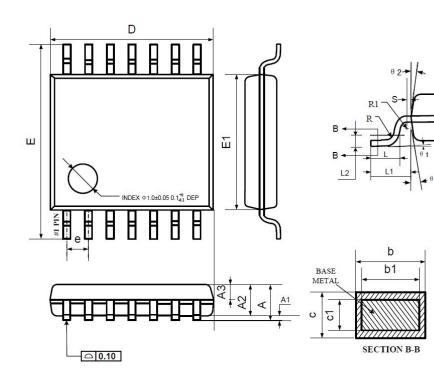
RI R	
+ - + h+	

A2 A

Symbol	Dimensions In Millimeters				
-0	MIN	NOM	MAX		
A	1.35	1.60	1.75		
A1	0.10	0.15	0.25		
A2	1.25	1.45	1.65		
A3	0.55	0.65	0.75		
b	0.36		0.49		
b1	0.35	0.40	0.45		
С	0.16		0.25		
c1	0.15	0.20	0.25		
D	8.53	8.63	8.73		
E	5.80	6.00	6.20		
E1	3.80	3.90	4.00		
e		1.27 BS0	0		
L	0.45	0.60	0.80		
L1		1.04 RE			
L2		0.25 BS0	0		
R	0.07				
R1	0.07				
h	0.30	0.40	0.50		
θ	0°		8°		
01	6°	8°	10°		
θ2	6°	8°	10°		
03	5°	7 °	9°		
04	5°	7 °	9°		



5.5 TSSOP14 (Package Outline Dimensions)



Symbol	Dimensions In Millimeters				
	MIN	NOM	MAX		
A			1.20		
A1	0.05	—	0.15		
A2	0.90	1.00	1.05		
A3	0.34	0.44	0.54		
b	0.20	—	0.28		
b1	0.20	0.22	0.24		
С	0.10		0.19		
c1	0.10	0.13	0.15		
D	4.86	4.96	5.06		
Е	6.20	6.40	6.60		
E1	4.30	4.40	4.50		
е		0.65 BSC	2		
L	0.45	0.60	0.75		
L1		1.00 REF			
L2		0.25 BSC)		
R	0.09	-	-		
R1	0.09				
S	0.20				
θ1	0°		8°		
θ2	10°	12°	14°		
0 3	10°	12°	14°		

6. Related Parts

Part Number	Description
COS6041/2/4	24kHz, 0.5µA, RRIO Op Amps, 1.8 to 5.5V Supply
COS1347/2347/4347	350kHz, 15µA, RRIO Op Amps, 1.8 to 5.5V Supply
LM321/2/4	1.5MHz, 50µA, RRIO Op Amps, 1.8 to 5.5V Supply
COS1314/2314/4314	3MHz, 150µA, RRIO Op Amps, 1.8 to 5.5V Supply
COS821/2/4	5MHz, 300µA, RRIO Op Amps, 1.8 to 5.5V Supply
COS1374/2374/4374	7MHz, 500µA, RRIO Op Amps, 1.8 to 5.5V Supply
COS721/2/4	10MHz, 650µA, RRIO Op Amps, 2.1 to 5.5V Supply
COS1333/2333/4333	0.35MHz, 18µA, RRIO Op Amps, 1.8 to 5.5V Supply, Zero Drift, Vos<20µV
COS8551/2/4	1.5MHz, 55 μ A, RRIO Op Amps, 1.8 to 5.5V Supply, Zero Drift, Vos<10 μ V